

S2000AF

High voltage NPN power transistor for standard definition CRT display

Features

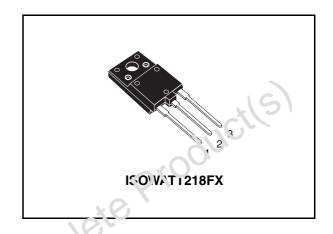
- State-of-the-art technology:
 - Diffused collector "Enhanced generation"
- Stable performances versus operating temperature variation
- Low base-drive requirement
- Tigh h_{FE} range at operating collector current
- High ruggedness
- Fully insulated power package U.L. compliant

Applications

- Horizontal deflection output for CRT TV
- Switch mode power supplies for CRT TV



The S2000AF is manufactured using dinfused collector in planar technology adopting new and enhanced high voltage structure for updated performance to the horizontal deflection stage.



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SC06960

Internal schematic diagram

Table 1. Device summary

Order code	Marking	Package	Packaging
S2000AF	S2000AF	ISOWATT218FX	Tube

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Content S2000AF

Content

1	Electrical ratings 3
2	Electrical characteristics 4
	2.1 Electrical characteristics (curves)
	2.2 Test circuits
3	Package mechanical data 8
4	Revision history
	Obsolete '
	Product(s)
005	Electrical characteristics

S2000AF Electrical ratings

1 Electrical ratings

Table 2. Absolute maximum rating

Symbol	Parameter	Value	Unit
V _{CES}	Collector-emitter voltage (V _{BE} = 0)	1500	V
V _{CEO}	Collector-emitter voltage (I _B = 0)	700	V
V _{EBO}	Collector-base voltage (I _C = 0)	9	V
I _C	Collector current	8	Α
I _{CM}	Collector peak current (t _P < 5ms)	15	А
I _B	Base current	4.0	Α
P _{TOT}	Total dissipation at T _c = 25°C	5 0	W
V _{ins}	Insulation withstand voltage (RMS) from all three leads to external heatsink		V
T _{stg}	Storage temperature	-65 to 150	°C
T _J	Max. operating junction temperature 150]

Table 3. Thermal data

	Symbol	Parameter		Value	Unit °C/W	
	R _{thj-case} Thermal resistance junction-case max		max	2.5		
,so)	eteP	rodulo				
0/050						

S2000AF **Electrical characteristics**

Electrical characteristics 2

(T_{case} = 25°C unless otherwise specified)

Electrical characteristics Table 4.

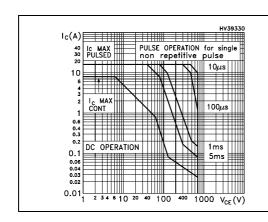
Symbol	Parameter	Test cond	itions	Min.	Тур.	Max.	Unit
I _{CES}	Collector cut-off current (V _{BE} =0)	V _{CE} = 1500V V _{CE} = 1500V;	T _C = 125°C			0.2 2	mA mA
I _{EBO}	Emitter cut-off current (I _C =0)	V _{EB} = 9V				1 -	mA
V _{CEO(sus)} (1)	Collector-emitter sustaining voltage (I _C =0)	I _C = 100mA		700	40		V
V _{CE(sat)} (1)	Collector-emitter saturation voltage	I _C = 4.5A I _C = 4.5A	I _B = 2A I _B = 1,	10		1 5	V
V _{BE(sat)} (1)	Base-emitter saturation voltage	I _C = 4.5A	1 ₃ = 1A			1.2	V
h _{FE} ⁽¹⁾	DC current gain	$I_C = 1A$ $I_C = 1$	$V_{CE} = 5V$ $V_{CE} = 5V$	10 4.5		30 9	
t _s t _f	Inductive load Storage time Fall time	$I_C = 4.5A$ $I_{BE(off)} = -2.7V$ $I_{BB(off)} = 4.5\mu H$	$B(on) = 0.5A$ $f_h = 16KHz$		2.5 0.2		μs μs
1. Pulsed: Pul	lse duration = 3J0 ms, duty cyc	ele 1.5 %					

^{1.} Pulsed: Pulse duration = 300 ms, duty cycle 1.5 %

2.1 Electrical characteristics (curves)

Figure 2. Safe operating area

Figure 3. Derating curve



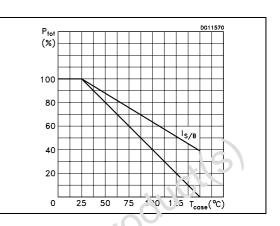
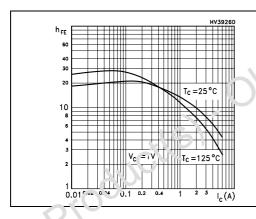


Figure 4. DC current gain

Figure 5. DC ourrent gain



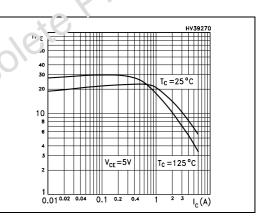
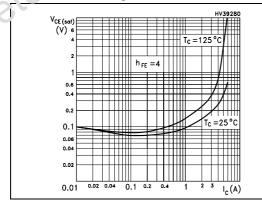
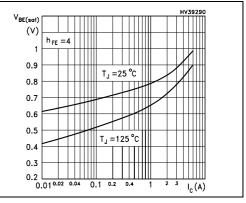


Figure 6. Collector-emitter saturation voltage

Figure 7. Base-emitter saturation voltage

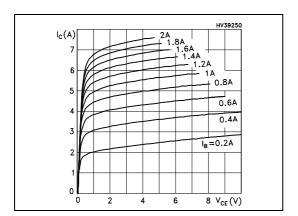




577

Electrical characteristics S2000AF

Figure 8. Output characteristics



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2.2 Test circuits

Figure 9. Power losses and inductive load switching

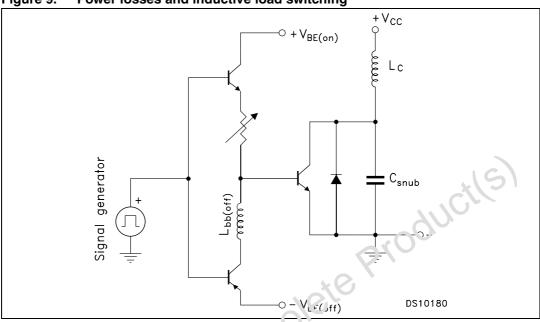
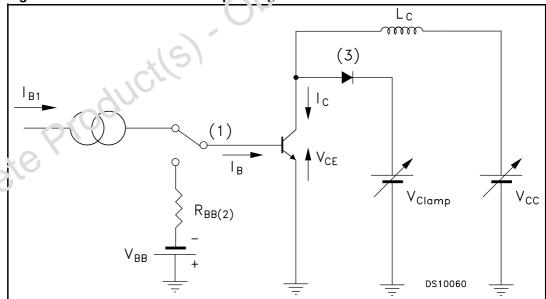


Figure 10. Reverse biased safe operating area



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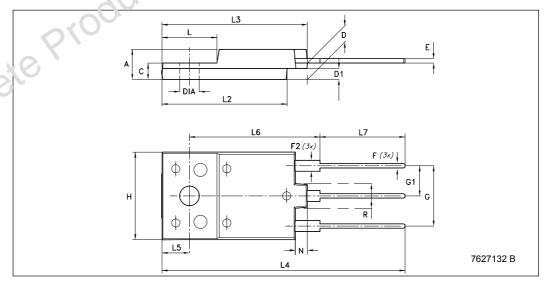
3 Package mechanical data

In order to meet environmental requirements, ST offers these devices in ECOPACK® packages. These packages have a Lead-free second level interconnect. The category of second level interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at: www.st.com

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ISOWATT218FX mechanical data

Dim.		mm.		
Dilli.	Min.	Тур	Max.	
Α	5.30		5.70	
С	2.80		3.20	
D	3.10		3.50	
D1	1.80		2.20	
E	0.80		1.10	
F	0.65		0.95	
F2	1.80		2.20	
G	10.30		1 .50	
G1		5.45	70,	
Н	15.30		15.70	
L	9		10.20	
L2	22.80	.0.	23.20	
L3	26.30	10,10	26.70	
L4	43.20		44.40	
L5	4.30	-105	4.70	
L6	24.30		24.70	
L7	14.60		15	
N	1.80		2.20	
R	380		4.20	
Dia	3.40		3.80	



577

Revision history S2000AF

4 Revision history

Table 5. Document revision history

Date	Revision	Changes
02-Mar-2007	1	Initial release.
14-Aug-2007	2	Complete document, added all curves (2.1: Electrical characteristics (curves)

Obsolete Product(s). Obsolete Product(s)

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577

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